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Formation of one-dimensional self-assembled silicon nanoribbons on Au(110)-(2 × 1)

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We report results on the self-assembly of silicon nanoribbons (NRs) on the (2 × 1) reconstructed Au(110) surface under ultra-high vacuum conditions. Upon adsorption of 0.2 monolayer (ML) of silicon, the (2 × 1) reconstruction of Au(110) is replaced by an ordered surface alloy. Above this coverage, a new superstructure is revealed by low energy electron diffraction (LEED), which becomes sharper at 0.3 Si ML. This superstructure corresponds to Si nanoribbons all oriented along the $[\bar{1}10]$ direction as revealed by LEED and scanning tunneling microscopy (STM). STM and high-resolution photoemission spectroscopy indicate that the nanoribbons are flat and predominantly 1.6 nm wide. In addition, the silicon atoms show signatures of two chemical environments corresponding to the edge and center of the ribbons. © 2013 American Institute of Physics. [<http://dx.doi.org/10.1063/1.4793536>]

The remarkable properties of graphene have encouraged scientists to explore the feasibility of silicene, the analogue of graphene for silicon atoms.^{1–5} Calculations have shown that silicene has an intrinsic stability and presents electronic properties similar to those of graphene.⁵ From the experimental point of view, silicene was grown first on Ag(110)^{6–9} and then on Ag(111) surfaces.^{10–13} Deposition of silicon on a Ag(110) surface produces 1.6 nm wide silicene nanoribbons (NRs) with a honeycomb structure.⁷ Evidence of a strong metallic character in these NRs was provided by high-resolution photoemission spectroscopy (HR-PES) measurements.⁶ These data show quantized states in the valence band presenting one-dimensional (1D) dispersion along the NRs.⁹ In addition, the oxidation of the NRs was shown to be less efficient compared to the oxidation of silicon surface.¹⁴ On the Ag(111) surface, the growth of a continuous 2D sheet of silicene with large areas of an almost defect free honeycomb structure presenting a $(2\sqrt{3} \times 2\sqrt{3}) R30^\circ$ superstructure has been observed by STM.¹¹ Theoretical simulations (DFT/GGA) performed on this system confirm the stability of such a structure.⁷ Recently, several experimental studies have independently reported the growth of silicene on the Ag(111) surface, revealing the existence of different ordered phases.^{12,13} On both the (111) and (110) faces, the different phases are related to the intrinsic perfect match between four nearest neighbor Ag-Ag distances (1.156 nm) and three unit cells of the (111) surface of silicon (1.152 nm).

We have studied the growth of Si on Au.¹⁵ Indeed Au is also suitable substrate because the Si-Au system presents a tendency to phase separation like Si-Ag.¹⁶ In addition, the lattice parameter of Au (0.409 nm) is very close to that of Ag (0.408 nm) and the Si surface energy (1.200 J/m²) is smaller than that of Au (1.506 J/m²).¹⁷ From this point of view, we can expect the formation of silicene NRs on top of the Au(110) surface similar to those on Ag(110).

Recently, the formation of a 2D crystal (Au–Si alloy) floating on top of the eutectic liquid has been reported.^{18–20} During the first stages of silicon deposition on Au(110)-(2 × 1), we also observed a new ordered 2D surface alloy when the substrate is held at the eutectic temperature (~400 °C).¹⁵ In this Letter, we present the growth characteristics of silicon NRs on Au(110) as well as their electronic properties. We show that exposure of the ordered Au–Si alloy surface layer to silicon results in parallel assembly of straight silicon NRs. The NRs have the same orientation and a predominantly characteristic narrow width of 1.6 nm, with lengths reaching a few hundreds of nanometers, limited only by the Au(110) terrace width.

The experiments were performed under ultra-high vacuum (UHV) using the standard tools for surface preparation and characterization: an ion gun for surface cleaning, a low energy electron diffractometer (LEED) for structural characterization, a STM for surface characterization at the atomic scale working at room temperature (RT), and an Auger electron spectrometer (AES) for chemical surface analysis and calibration of the silicon coverage. The Au(110) sample was cleaned by several cycles of sputtering (600 eV Ar⁺ ions,

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$p = 5 \times 10^{-5}$ mbar) and annealing at 450°C until a sharp $p(2 \times 1)$ LEED pattern was obtained. Silicon, evaporated by direct current heating of a piece of Si wafer, was deposited onto the Au(110) surface held at a temperature of 400°C . The temperature was controlled by a thermocouple located close to the sample. The same crystal was studied in ISMO-Orsay for the LEED/STM experiments²¹ and at the University of Zurich for detailed LEED analysis.²² The HR-PES angle-integrated measurements of the Si $2p$ and Au $4f$ core-levels were performed at RT on the TEMPO beam-line of the synchrotron SOLEIL.²³

Figure 1(a) shows the (2×1) LEED pattern characteristic of the bare Au(110) surface reconstruction. During silicon deposition on the Au(110) substrate held at 400°C , the (2×1) starts to disappear while a new superstructure appears at a Si coverage of ~ 0.2 monolayer (ML), which was shown to correspond to an ordered 2D surface alloy.¹⁵ Above this coverage, the diffraction spots corresponding to the 2D surface alloy disappear, and a rectangular superstructure appears, becoming sharp at 0.3 Si ML. The corresponding LEED pattern is shown in Figure 1(b). The $6 \times$ periodicity is very clear along the $[\bar{1}10]^*$ while the spots along $[001]^*$ direction are not very distinct showing different spacing, suggesting a variable short-range order along this direction.

The STM images were recorded after the sample had been cooled down to RT. Figure 2(a) shows an atomically resolved filled-state STM image of the bare Au(110)- (2×1) surface. The missing-row structure of the Au(110)- (2×1) reconstruction is clearly observed. Figure 2(b) displays the STM topography of the silicon NRs formed after the deposition of 0.3 ML silicon at 400°C . These NRs are all perfectly aligned along the $[\bar{1}10]$ direction of the Au(110) surface. Only the surface steps limit the length of these nanoribbons, and they have a low density of defects. In Figure 3(a), the periodicity of 1.76 nm along the $[\bar{1}10]$ direction (see also, the line profile presented in Figure 3(b)) matches the periodicity of $6 \times a_1 = 1.734$ nm ($a_1 = 0.289$ nm) seen in the LEED pattern of Figure 1(b). The $6 \times$ periodicity indicates that the NRs are not made of Si $[\bar{1}10]$ rows with a “bulk-like” interatomic distance. In such a case, a $4 \times$ periodicity would be expected, given the excellent match expected between four Au atomic distances (4×0.289 nm = 1.156 nm) and three silicon distances along Si $[\bar{1}10]$ (3×0.385 nm = 1.155 nm). The line profile presented in Figure 3(c) shows that these NRs have a width of 1.6 nm, which corresponds to $4 \times a_2 = 1.636$ nm ($a_2 = 0.409$ nm) atomic distances along the $[001]$ Au direction and a maximum apparent height of 0.24 nm

FIG. 1. LEED pattern recorded at $E_p = 40$ eV corresponding to: a) the (2×1) reconstruction of the bare Au(110) surface (black rectangle), b) the $6 \times$ superstructure is visible inside the 2×1 rectangle after the deposition of ~ 0.3 Si ML on Au(110) held at 400°C .

FIG. 2. (a) atomically resolved filled-states STM image of the clean Au(110)- (2×1) reconstruction (4×4 nm², $V = -80$ mV, and $I = 2.2$ nA). (b) STM image of the surface at 0.3 Si ML coverage showing NRs oriented along the $[\bar{1}10]$ direction (60×60 nm², $V = -0.2$ V, and $I = 1.9$ nA).

(atomic height). In addition, the height profile of Figure 3(c) also shows that the NRs are asymmetric across their widths.

Figures 4(a) and 4(b) show the Au $4f$ core level recorded on the pristine Au(110)- (2×1) surface at normal and at surface sensitive emission (75° with respect to the substrate normal), respectively, as well as their de-convolutions into two spin-orbit split components (B) and (S) located at 84.01 eV and 83.65 eV binding energies, respectively. A polynomial type secondary electron background is used, and all spectra are fitted with a Doniach-Sunjc line shape.²⁴ To deconvolute the Au $4f$ core level of the pristine surface, the following parameters were used: Gaussian widths of 115 meV and 150 meV for the components (B) and (S), respectively, and a 320 meV Lorentzian width with an asymmetry parameter equal to 0.02. The spin-orbit splitting was 3.678 eV, and the branching ratio was 0.66. Because its intensity increases in the surface sensitive emission mode, the (S) component is attributed to the surface Au atoms while the (B) component corresponds to Au atoms in a bulk environment. The surface-atom component is located 0.36 eV below the bulk binding energy, which is in good agreement with the value reported in previous studies.^{25–27}

Figures 4(c) and 4(d) show the Au $4f$ core level spectra, recorded at normal and at surface sensitive emission, respectively, after growing Si NRs on the surface (0.3 Si ML). Two spin-orbit split components (B) and (S') are necessary to fit the spectra, with the (B) component still located at the same

FIG. 3. (a) High resolution STM image showing the structure of the 1.6 nm wide Si NRs. (8×8 nm², $V = -64$ mV, and $I = 3.5$ nA). (b) Line profile along A showing the $6 \times$ periodicity. (c) Line profile along B showing the asymmetry across the width of the NR.

FIG. 4. Au 4f core levels spectra (dots) and their deconvolutions (solid line overlapping the data points) with two asymmetric components (B) and (S) recorded at $h\nu = 147$ eV for ((a) and (b)) the pristine Au(110)-(2 $\times$ 1) and ((c) and (d)) after deposition of 0.3 Si ML. The spectra (a) and (c) are recorded in normal emission while the spectra (b) and (d) are recorded in at 75° off-normal. The fitting parameters applied to the spectra of the pristine Au(110)-(2 $\times$ 1) are described in the main text. The (S) and (B) components are attributed to the surface and bulk Au atoms, respectively, of the pristine Au(110)-(2 $\times$ 1) while the (S') component corresponds to Au atoms bonded with Si atoms.

binding energy of 84.01 eV as the bulk component of the Au substrate (Figure 4(a)). However, the component (S') is now located at a binding energy of 84.60 eV, compared to 83.65 eV for the bare Au(110)-(2 $\times$ 1) surface. This component is now located at an energy 0.6 eV above the bulk binding energy. The Gaussian widths used to fit the components (B) and (S') are 215 meV and 415 meV, respectively, while the Lorentzian width and the asymmetry parameters are the same as in the pristine Au(110)-(2 $\times$ 1) surface. We also observe that the intensity of the component (S') increases in the surface sensitive emission mode, which indicates that it corresponds to the surface Au atoms with a Si environment. It is known that the (2 $\times$ 1) reconstruction is induced by the strain derivative of surface energy in the non-reconstructed Au(110) surface.²⁸ On the other hand, adsorbed atoms can affect the surface reconstruction of metallic (110) surfaces through charging because of the difference in the atomic work functions.²⁹ Our experiment shows that the (2 $\times$ 1) reconstruction of the Au(110) surface disappears upon Si

adsorption. This explains why the component (S) vanishes and the component (S') appears. We have shown previously that the (2 $\times$ 1) reconstruction of Au(110) is replaced by an ordered surface alloy.¹⁶ After the formation of the Si NRs, the LEED experiments do not show the (2 $\times$ 1) reconstruction.

The 2p core level spectra of the adsorbed silicon are shown in Figures 5(a) and 5(b). The Si 2p spectra of the Si NRs are recorded at normal and surface sensitive emission together with their de-convolutions into two spin-orbit split components (S1) and (S2) located at 99.76 eV and 99.58 eV, respectively. These indicate two Si environments within the Si NRs. The fitting parameters used are: 150 meV Gaussian width for the (S1) component and 215 meV for the (S2) component; and an 80 meV Lorentzian width. The spin-orbit splitting is 0.605 eV, and the branching ratio is 0.52. The best fit is obtained after including an asymmetry parameter of 0.09, which is higher than the 0.02 asymmetry parameter for the Au 4f core levels. This is evidence for metallicity of the Si NRs. The very narrow total widths of the components, 130 meV for (S1) and 210 meV for (S2) indicate a high ordering of the Si atoms within the NRs. The Si 2p core-levels spectra measured at normal emission and at surface sensitive emission are almost identical, with the same ratio between the two components. This indicates that all Si atoms

FIG. 5. Si 2p core levels spectra (dots) and their de-convolutions (solid line overlapping the data points) with two asymmetric components (S1) and (S2) recorded after deposition of 0.3 Si ML on Au(110)-(2 $\times$ 1) at $h\nu = 147$ eV in (a) normal emission and (b) 75° off-normal. The fitting parameters are described in the main text. The (S1) and (S2) components are assigned to the center and the edge Si atoms, respectively.

are located on the surface and at a similar height in agreement with the STM images of the Si NRs.

We observe that the Si NRs obtained on Au(110)-(2×1) present similarities with those obtained on the Ag(110) surface.^{6–9} Both are metallic and present protrusions within the NRs larger than one atom size, they are 1.6 nm wide, and they are asymmetric across their width. The HR-PES study indicates that, in both cases, Si atoms are present in two different environments. We have shown in the high resolution STM images of NRs on Ag(110), a honeycomb structure which is evidence for silicene.⁷

However, in the present experimental study, the atomic resolution of the honeycombs for Si/Au(110) is not seen in the STM topographies. This might be related to electron quantum interference at the NR edges as seen in graphene.³⁰ The STM images obtained routinely on Ag(110) also present protrusions larger than one atom size⁹ suggesting similar behavior. Hence we deduced that the Si NRs formed on Au(110)-(2×1) could be silicene NRs.

It should be noted that complex Au/Si structures have been reported, such as the 6×6 structure of Au/Si(111)³¹ and also the formation of an ordered surface alloy on Au(110).¹⁵ For the nano-ribbon phase reported here, considerations of the coincidence with the lattice of silicene allow the proposition of a simple ribbon model as indicated in Figure 6(b). Along the close packed $[\bar{1}10]$ direction, 6 Au atomic distances fit on 5 silicene unit cells with a lattice constant of 0.346 nm. Along the $[100]$ direction, the ribbon width of about 4 Au lattice constants corresponds well with the width of 4 silicene rows. The Si-Si in-plane nearest neighbor lateral distance deduced from this model is 0.2 nm close to the value found for a silicene sheet on Ag(111).¹¹ If there is some buckling as it was shown for silicene on Ag(111),^{5–32} the apparent lateral Si-Si distance here of 0.2 nm will be shorter than the real Si-Si bond length. The model presents an asymmetry across the width of the Si NR in good

agreement with the STM image (Figure 6(a)). In addition, the model shows that the silicon NRs are composed of five zig-zag chains of Si atoms running the length of the ribbon. Two zig-zag chains (one on each side of the ribbon) compose the edge of the NR, resulting in a fraction of 0.4 for the edge atoms in the unit cell. If we assign the (S1) component to the center atoms and the (S2) component to the edge atoms, their relative intensities are, respectively, 0.52 and 0.48 (measured) in qualitative agreement with the respective 0.6 and 0.4 fraction (from the model).

In conclusion, we have grown silicon NRs on Au(110) that are 1.6 nm wide with a periodicity $6 \times$ along the NR, as indicated by STM images and are similar to those obtained on Ag(110), in earlier experiments. High-resolution photoemission spectroscopy data on the silicon core levels indicate the presence of Si atoms in two environments (edge and middle atoms). In addition, our analysis also indicates that all Si atoms occupy the same height above the Au surface with a clear metallic character, hinting that silicene NRs on Au(110), have been grown. Atomistic calculations in progress will clarify the structure of these Si NRs.

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FIG. 6. (a) STM image of a Si NR showing the internal order with the asymmetry across its width. (b) Proposed model based on the STM image and the LEED pattern. The Si NR with zig-zag edges is presented by a black honeycomb lattice. The atoms of the 1st and the 2nd Au layer are in light gray and dark gray, respectively. The asymmetry across the width of the NR is highlighted. The Au atoms corresponding to the corners of the lozenge are in blue.

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